

**DESCRIPTION**

This is a Silicon P-Type PIN Quadrant detector designed for use in precision guidance and laser tracking applications.

**FEATURES**

- High Responsivity @ 1.06  $\mu\text{m}$ , 0.45 A/W typical
- Sensitivity range 600-1100 nm
- Four Quadrant Geometry w/guard ring
- 3.5 mm Diameter Active Area

**ABSOLUTE MAXIMUM RATINGS**

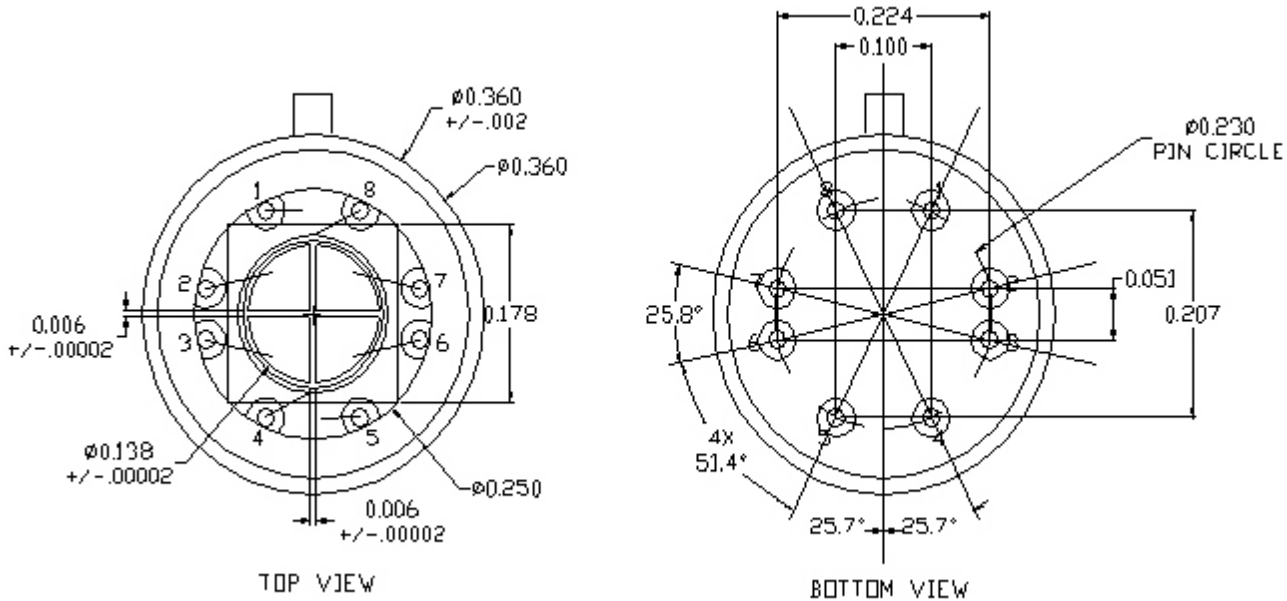
- Storage temperature..... -54°C to +125°C
- Case operating temperature... -54°C to +100°C
- Lead solder temperature..... 260°C, 10 seconds
- Supply Voltage..... +250 Volts

**OPERATING CONDITIONS**

- Supply Voltage..... 180 Volts
- Forward Voltage..... 0.5 Volts
- Power Dissipation (per quadrant, 25°C).. 500 mW
- Noise Current.....  $0.5 \times 10^{-13}$  A/Hz

**ELECTRO-OPTICAL CHARACTERISTICS (Case T = 25°C)**

| PARAMETER         | TEST CONDITION  | SYMBOL   | MIN  | TYP  | MAX | UNIT  |
|-------------------|---|----------|------|------|-----|-------|
| Breakdown Voltage | $I_R = 100 \mu\text{A}, H = 0 \text{ mW/cm}^2$                                  | $V_{BR}$ | 250  |      |     | Volts |
| Dark Current      | $V_R = 180\text{V}, H = 0 \text{ mW/cm}^2$                                      | $I_D$    |      | 30   | 100 | nA    |
| Capacitance       | $V_R = 180\text{V}, f = 1 \text{ MHz}$  | $C_T$    |      | 10   | 12  | pF    |
| Crosstalk         | $V_R = 180\text{V}$   |          |      |      | 1   | %     |
| Response Time     | 10%-90%, $\lambda = 1.06 \mu\text{m}$<br>$V_R = 180 \text{ V}, R_L = 50 \Omega$ | $t_r$    |      | 12   | 15  | nsec  |
|                   |   | $t_f$    |      | 12   | 20  | nsec  |
| Responsivity      | $V_R = 180\text{V}, \lambda = 1.06 \mu\text{m}$                                 | $R_e$    | 0.36 | 0.45 |     | A/W   |



Mechanical Tolerances:  $\pm 0.005$  inches, except where noted.

**PINOUT:**

- Pin 1: Common Anode
- Pin 2: Cathode 1
- Pin 3: Cathode 2
- Pin 4: Guard Ring Cathode
- Pin 5: Common Anode
- Pin 6: Cathode 3
- Pin 7: Cathode 4
- Pin 8: Guard Ring Cathode

